MAZ9xxxH Series

Silicon planar type

For surge absorption circuit

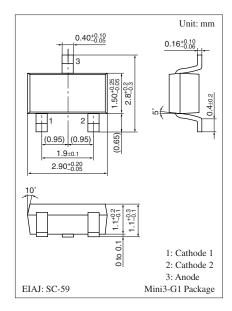
■ Features

- Two elements anode-common type
- Power dissipation P_D: 200 mW

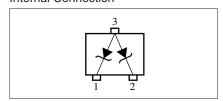
■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Power dissipation *	P_{D}	200	mW	
Junction temperature	T _j	150	°C	
Storage temperature	T_{stg}	-55 to +150	°C	

Note) *: $P_D = 200 \text{ mW}$ achieved with a printed circuit board.



Internal Connection



■ Common Electrical Characteristics $T_a = 25$ °C ± 3 °C

Parameter	Symbol		Conditions	Min	Тур	Max	Unit	
Zener voltage*	V _Z	I_Z	Specified value					V
Zener rise operating resistance	R _{ZK}	I_Z	Specified value	Refer to the list of the electrical characteristics				Ω
Zener operating resistance	R _Z	I _Z	Specified value	within part numbers				Ω
Reverse current	I_R	V _R	Specified value			_		μA

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

2. Electrostatic breakdown voltage: ±10 kV

Test method: IEC1000-4-2 (C = 150 pF, R = 330 Ω , Contact discharge: 10 times)

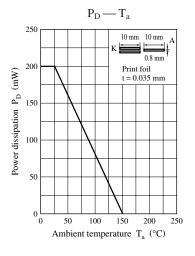
3. *: The temperature must be controlled 25°C for V_Z mesurement.

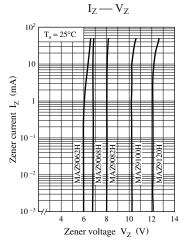
 V_Z value measured at other temperature must be adjusted to V_Z (25°C)

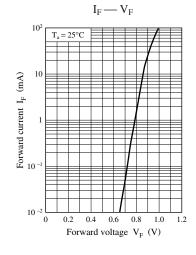
 V_Z guaranted 20 ms after current flow.

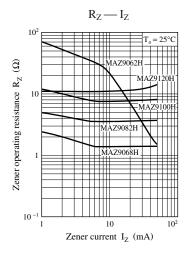
■ Electrical characteristics within part numbers $Ta = 25^{\circ}C \pm 3^{\circ}C$

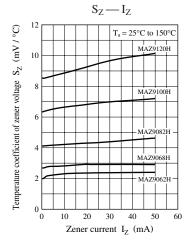
Part number	Zener voltage Part number V _Z (V)			Reverse current I _R (mA)		Zener operating resistance $R_Z(\Omega)$	Zener rise operating resistance $R_{ZK}(\Omega)$	Marking symbol	
	Min	Nom	Max	l _Z (mA)	Max	V _R (V)	$I_Z = 5 \text{ mA}$ Max	$I_Z = 0.5 \text{ mA}$ Max	
	IVIIII	NOITI	iviax	(IIIA)	IVIAX	(۷)	iviax	iviax	
MAZ9062H	5.8	6.2	6.6	5	0.2	4	50	100	6.2Z
MAZ9068H	6.4	6.8	7.2	5	0.1	4	30	60	6.8Z
MAZ9082H	7.7	8.2	8.7	5	0.1	5	30	60	8.2Z
MAZ9100H	9.4	10.0	10.6	5	0.05	7	30	60	10Z
MAZ9120H	11.4	12.0	12.7	5	0.05	9	30	80	12Z

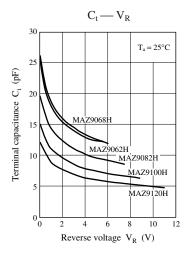












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